

Johann Osmond

List of Publications by Year in descending order

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Version: 2024-02-01

12

papers

1,344

citations

1040056

9

h-index

1372567

10

g-index

12

all docs

12

docs citations

12

times ranked

1850

citing authors

#	ARTICLE		IF	CITATIONS
1	Formamidinium Incorporation into Compact Lead Iodide for Low Band Gap Perovskite Solar Cells with Open-Circuit Voltage Approaching the Radiative Limit. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 9083-9092.		8.0	9
2	Natural Random Nanotexturing of the Au Interface for Light Backscattering Enhanced Performance in Perovskite Solar Cells. <i>ACS Photonics</i> , 2018, 5, 2243-2250.		6.6	39
3	Time-domain separation of optical properties from structural transitions in resonantly bonded materials. <i>Nature Materials</i> , 2015, 14, 991-995.		27.5	166
4	Emission Engineering in Germanium Nanoresonators. <i>ACS Photonics</i> , 2015, 2, 53-59.		6.6	27
5	Optical switching at 1.55 nm in silicon racetrack resonators using phase change materials. <i>Applied Physics Letters</i> , 2013, 103, .		3.3	185
6	40Gbit/s germanium waveguide photodetector on silicon. , 2012, , .			5
7	Zero-bias 40Gbit/s germanium waveguide photodetector on silicon. <i>Optics Express</i> , 2012, 20, 1096.		3.4	368
8	Quantum-confined Stark effect measurements in Ge/SiGe quantum-well structures. <i>Optics Letters</i> , 2010, 35, 2913.		3.3	61
9	40 Gb/s surface-illuminated Ge-on-Si photodetectors. <i>Applied Physics Letters</i> , 2009, 95, .		3.3	22
10	Ge-on-silicon waveguide photodetectors for optical telecommunications. <i>Proceedings of SPIE</i> , 2009, , .		0.8	0
11	42 GHz pin Germanium photodetector integrated in a silicon-on-insulator waveguide. <i>Optics Express</i> , 2009, 17, 6252.		3.4	456
12	Ge/Si (100) heterojunction photodiodes fabricated from material grown by low-energy plasma-enhanced chemical vapour deposition. <i>Thin Solid Films</i> , 2008, 517, 380-382.		1.8	6